2CL2J

100mA 15kV -Medium Current High Voltage Diodes

HVGT high voltage silicon rectifier diodes is made of high quality glass passivated chip and high reliability epoxy resin sealing structure, and through professional testing equipment inspection qualified after to customers.

FEATURES:

1. High reliability design.
2. High voltage design.
3. Low frequency .
4. Conform to RoHS.
5. Epoxy resin molded in vacuumHave anticorrosion in the surface.

APPLICATIONS:

1. High voltage multiplier circuit
2. High current and high voltage circuit.
3. General purpose high voltage rectifier.
4. Other .

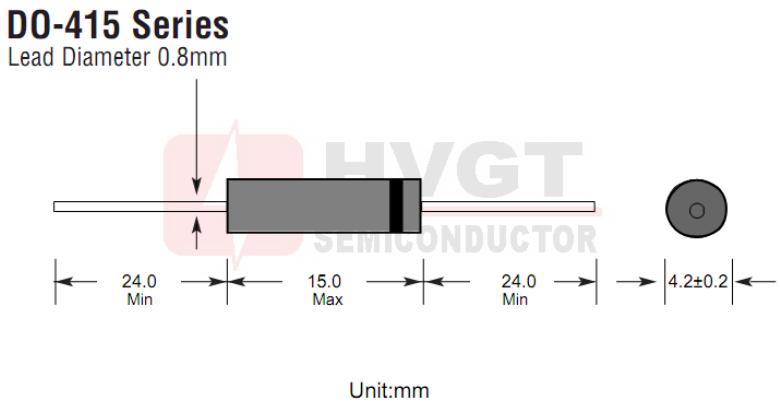
MECHANICAL DATA:

1. Case: epoxy resin molding.
2. Terminal: welding axis.
3. Net weight: 0.65 grams (approx).

SHAPE DISPLAY:



SIZE: (Unit:mm) **HVGT NAME: DO-415**



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MAXIMUM RATINGS AND CHARACTERISTICS: **(**Absolute Maximum Ratings)

Items	Symbols	Condition	Data Value	Units
Repetitive Peak Renerse Voltage	V_{RRM}	Ta=25°C;	15	kV
Average Output Current	I_F	Ta=25°C; Resistive Load	100	mA
Suege Current	I_{FSM}	Ta=25°C; 1/2 Sine(60Hz) ; 8.3mS	20	A
Junction Temperature	T_J		-40~+125	°C
Allowable Operation Case Temperature	Tc		125	°C
Storage Temperature	T_{STG}		-40~+125	°C

ELECTRICAL CHARACTERISTICS: Ta=25°C (Unless otherwise specified)

Items	Symbols	Condition	Data value	Units
Maximum Forward Voltage Drop	V_F	at 25°C;I_F =$I_{F(AV)}$	16	V
Maximum Reverse Current	I_R1	at 25°C;V_R =V_{RRM}	2.0	uA
	I_R2	at 100°C;V_R =V_{RRM}	40	uA
Maximum Reverse Recovery Time	T_{RR}	at 25°C; I_F=0.5I_R; I_R=I_{FAVM}; I_{RR}=0.25I_R	--	nS
Junction Capacitance	C_J	at 25°C; V_R=0V; f=1MHz	--	pF

Fig 1

Forward Current Derating Curve

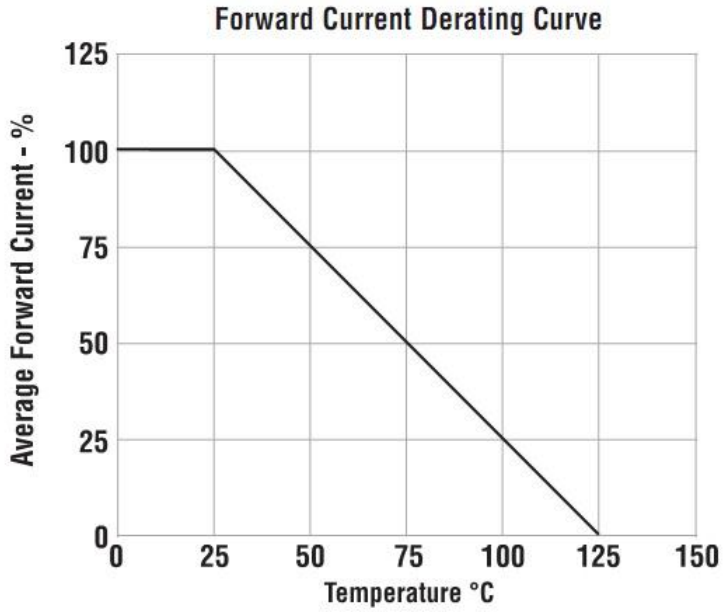
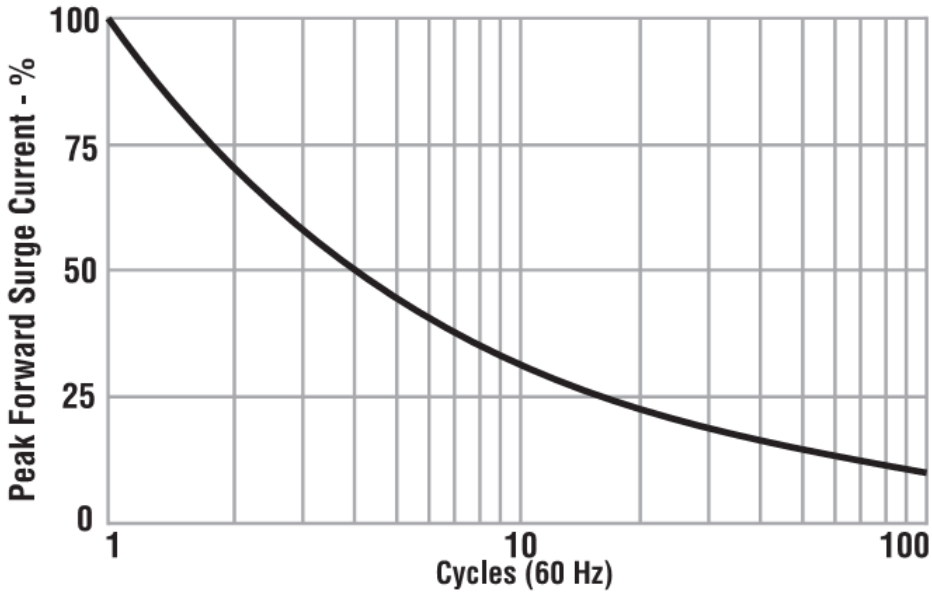


Fig 2

Repetitive Surge Current Derating Curve



This curve represents the percentage of published maximum surge rating as a function of surge repetition.

Marking	Type	Code	Cathode Mark
	2CL2J	2CL2J	